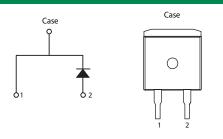
Littelfuse Power

LSIC2SD065D16A 650 V, 16 A SiC Schottky Barrier Diode

HF Rohs 🗭



Circuit Diagram TO-263-2L



Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature

Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "Pb-free" logo = 100 Pb-free lead plating

switch	ing	behav	vior
-	. •		

Extremely fast,

 Dramatically reduced switching losses compared to Si bipolar diodes

• Excellent surge capability

temperature-independent

• Solar inverters

- Industrial motor drives
- EV charging stations

Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	-	650	V	
DC Blocking Voltage	V _R	T _J = 25 °C	650	V	
		T _c = 25 °C	38	А	
Continuous Forward Current	I _F	T _c = 135 °C	17.2		
		$T_c = 140 \text{ °C}$	16		
Non-Repetitive Forward Surge Current	 _{FSM}	$T_c = 25 \text{ °C}, T_p = 10 \text{ ms}, \text{ Half sine pulse}$	70	A	
Power Dissipation	D	$T_c = 25 \text{ °C}$	125	- W	
Fower Dissipation	P _{Tot}	$T_c = 110 \text{ °C}$	54		
Operating Junction Temperature	T	-	-55 to 175	°C	
Storage Temperature	T _{stg}	-	-55 to 150	°C	
SolderingTemperature	T _{SOLD}	-	260	°C	

Electrical Characteristics (T _J = 25 °C unless otherwise specified)							
			Value				
Characteristics	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Forward Voltage	V _F	I _F = 16 Α, Τ _J = 25 °C	-	1.5	1.8	N	
		I _F = 16 A, T _J = 175 °C	-	1.85	-	V	
Reverse Current	I _R -	V _R = 650 V , T _J = 25 °C	-	<1	50	μA	
		V _R = 650 V , T _J = 175 °C	-	55	-		
Total Capacitance	C	V _B = 1 V, f = 1 MHz	-	730	-		
		V _R = 200 V, f = 1 MHz	-	92	-	pF	
		V _R = 400 V, f = 1 MHz	-	66	-		
Total Capacitive Charge	Q _c	$V_{R} = 400 \text{ V}, Q_{C} = \int_{0}^{V_{R}} C(V) dV$	-	48	-	nC	

Thermal Characteristics						
Characteristics	Symbol	Value	Unit			
Thermal Resistance	R _{euc}	1.2	°C/W			

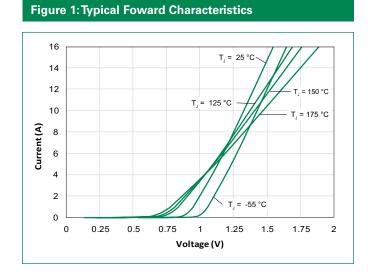


Figure 2: Typical Reverse Characteristics

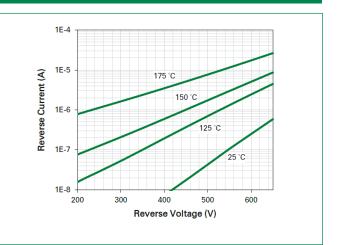


Figure 3: Power Derating

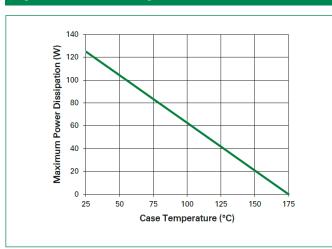
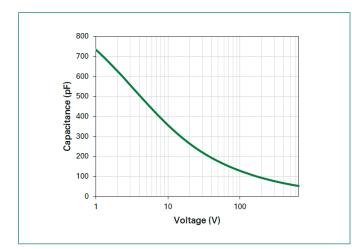
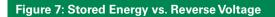


Figure 5: Capacitance vs. Reverse Voltage





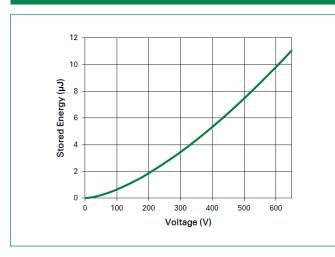


Figure 4: Current Derating

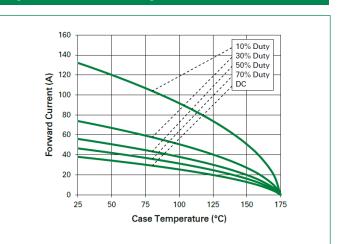


Figure 6: Capacitive Charge vs. Reverse Voltage

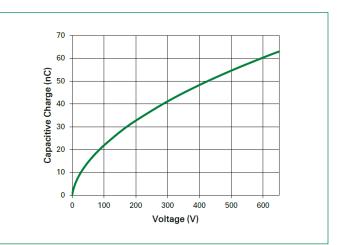
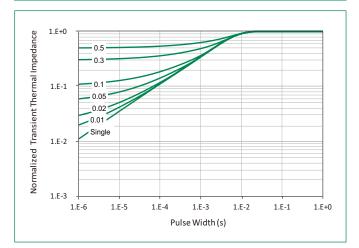
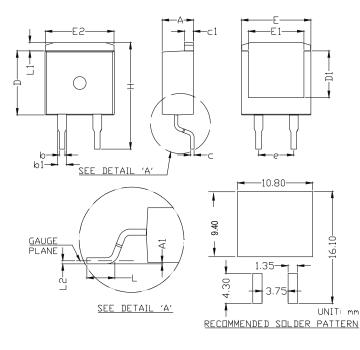


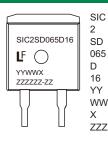
Figure 8: Transient Thermal Impedance



Dimensions-Package TO-263-2L



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- = SiC Diode = Gen2
- = Schottky Diode
- = Voltage Rating (650 V)
- = TO-263 Package (2 Lead) = Current Rating (16 A)
- = Year
- = Week
- = Special Code ZZZZZ-ZZ = Lot Number

Symbol	Millimeters				
Symbol	Min	Nom	Max		
А	4.30	4.50	4.70		
A1	0.00	-	0.25		
b	0.70	0.80	0.90		
b1	1.17	1.27	1.37		
С	0.46	0.50	0.60		
c1	1.25	1.30	1.40		
D	9.00	9.20	9.40		
D1	6.50	6.70	6.90		
Е	9.80	10.00	10.20		
E1	7.80	8.00	8.20		
E2	9.70	9.90	10.10		
е	5.08 BSC				
Н	15.00	15.30	15.60		
L	2.00	2.30	2.60		
L1	1.00	1.20	1.40		
L2	0.254 BSC				

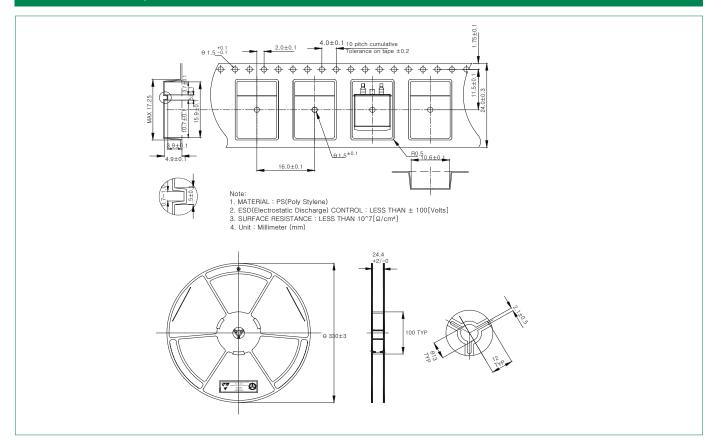
Packing Option

Part Number	Part Number Marking		M.O.Q
LSIC2SD065D16A	SIC2SD065D16	Tape and Reel	800



GEN2 SiC Schottky Diode LSIC2SD065D16A, 650 V, 16 A, TO-263-2L (D2PAK)

TO-263 Carrier Reel Specifications



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